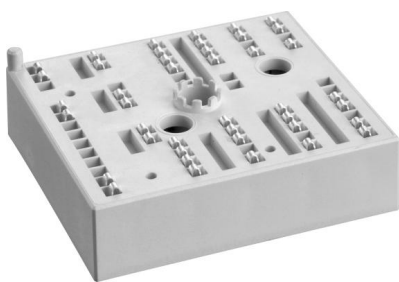


# SKiiP 24NAB126V1



MiniSKiiP® 2

3-phase bridge rectifier +  
brake chopper + 3-phase  
bridge inverter  
SKiiP 24NAB126V1

## Features

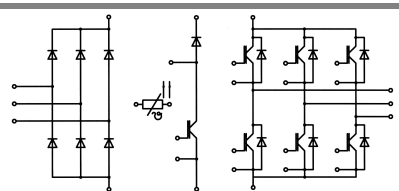
- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

## Typical Applications\*

- Inverter up to 19 kVA
- Typical motor power 11 kW

## Remarks

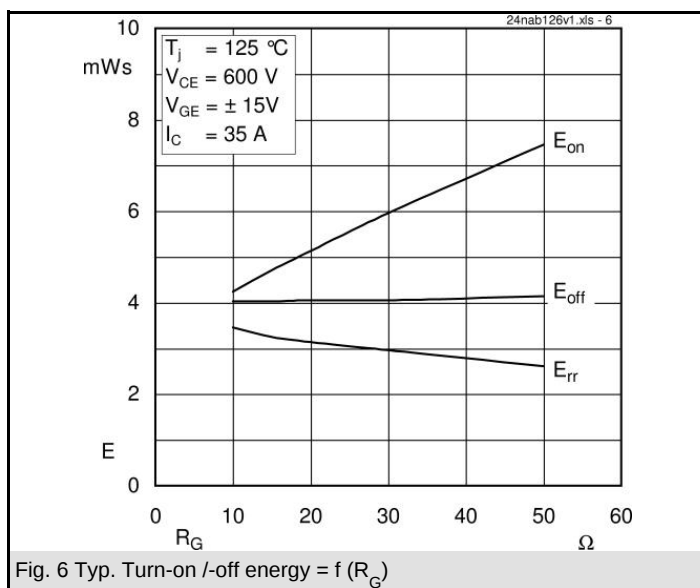
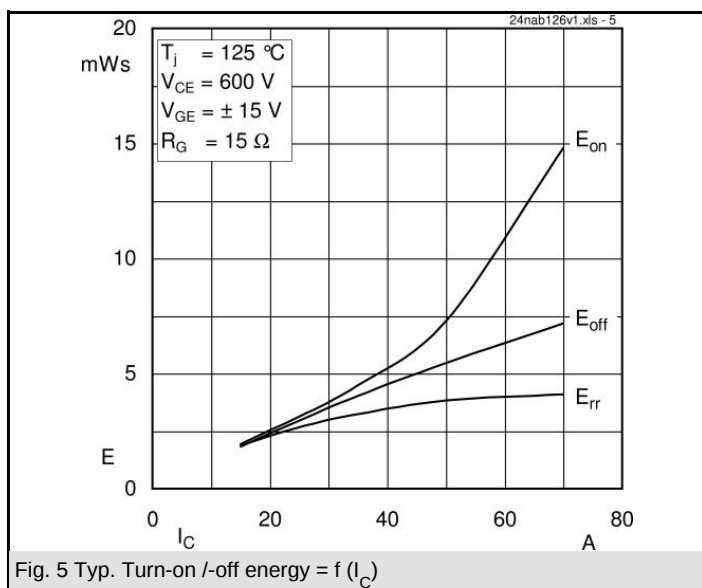
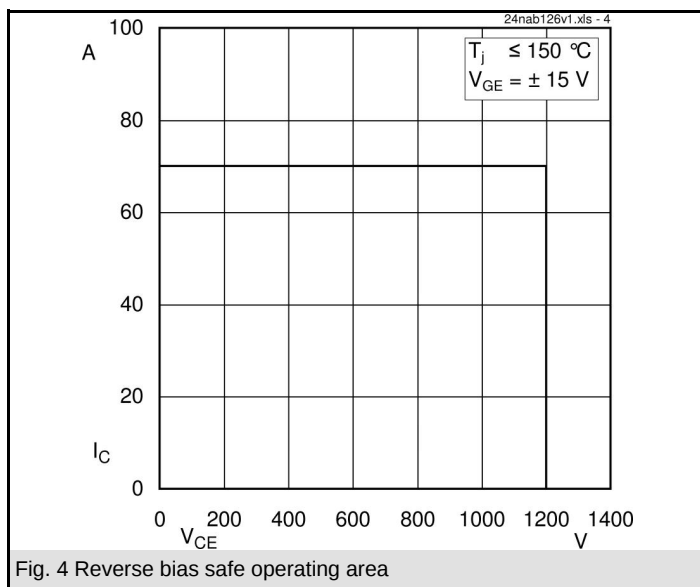
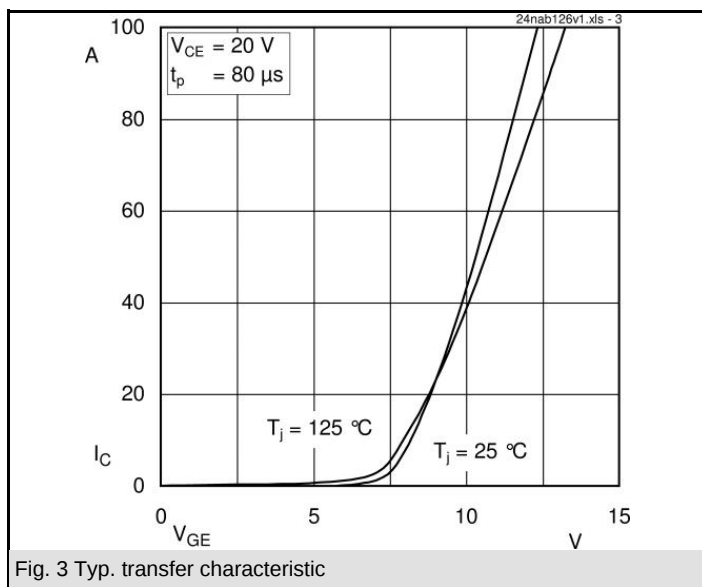
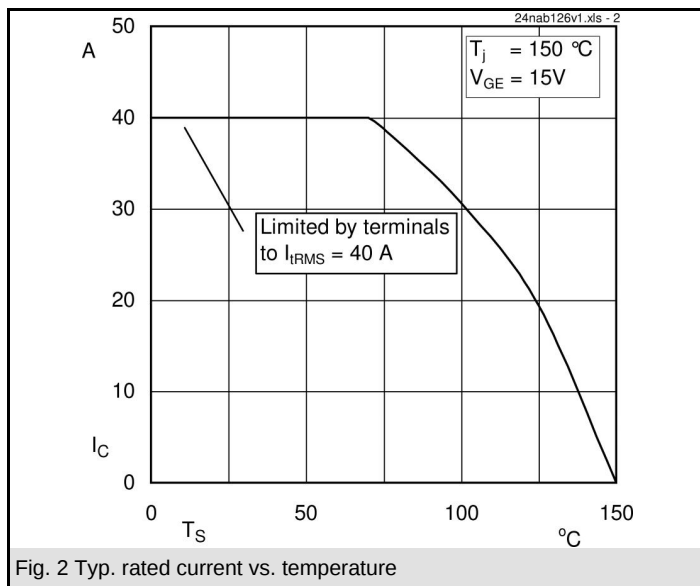
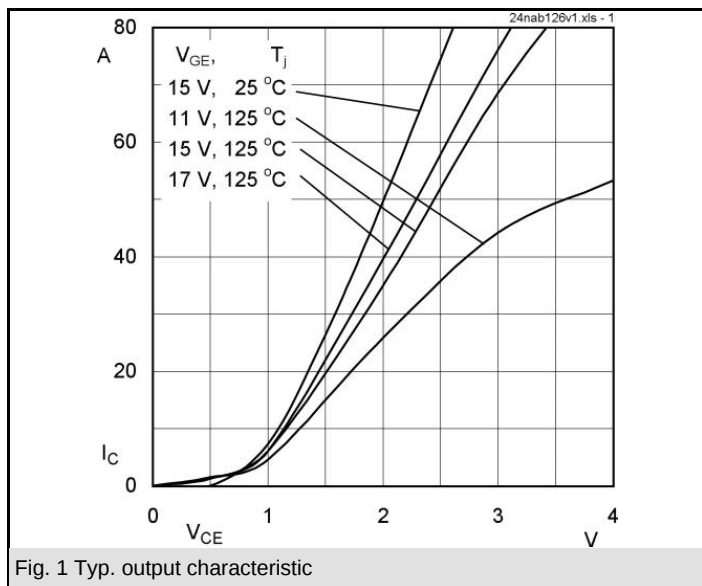
- $V_{CEsat}$ ,  $V_F$  = chip level value

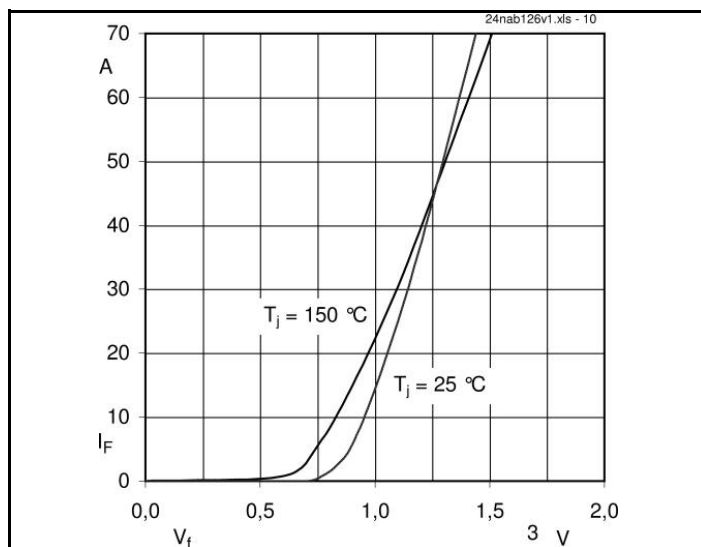
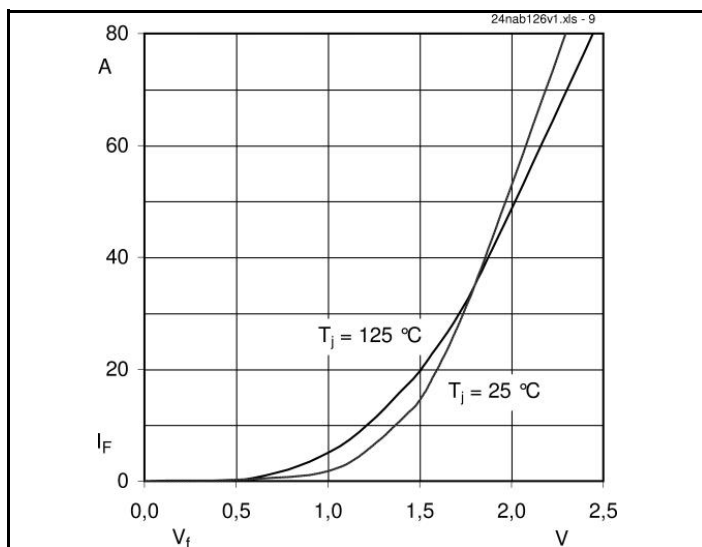
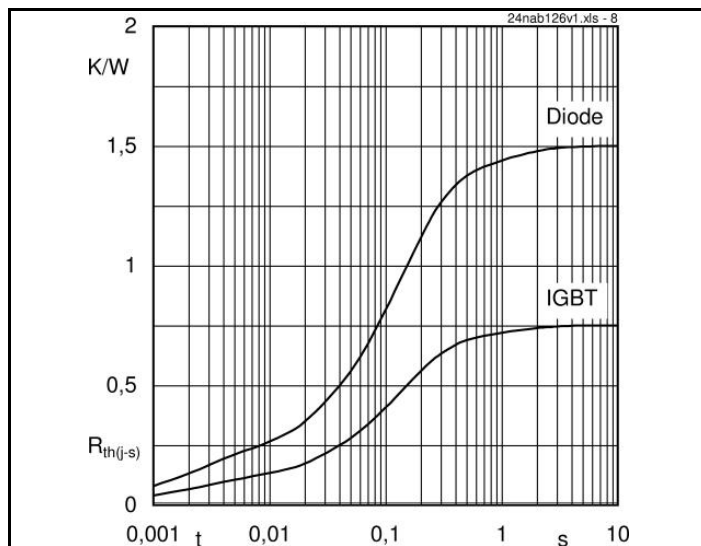
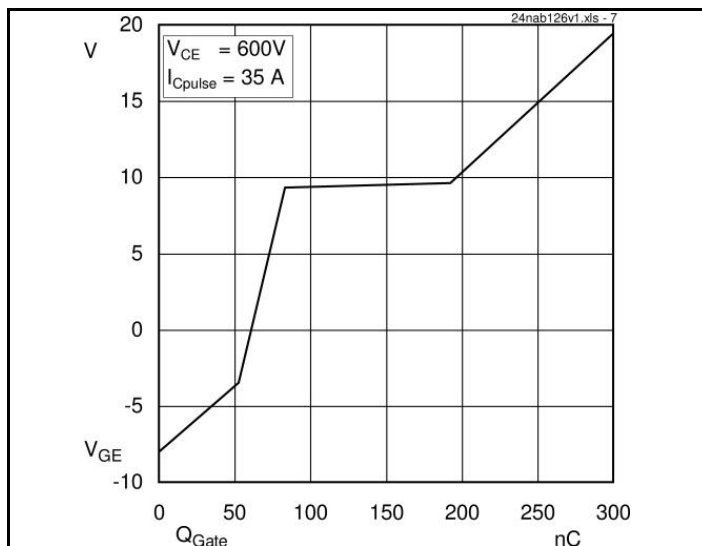


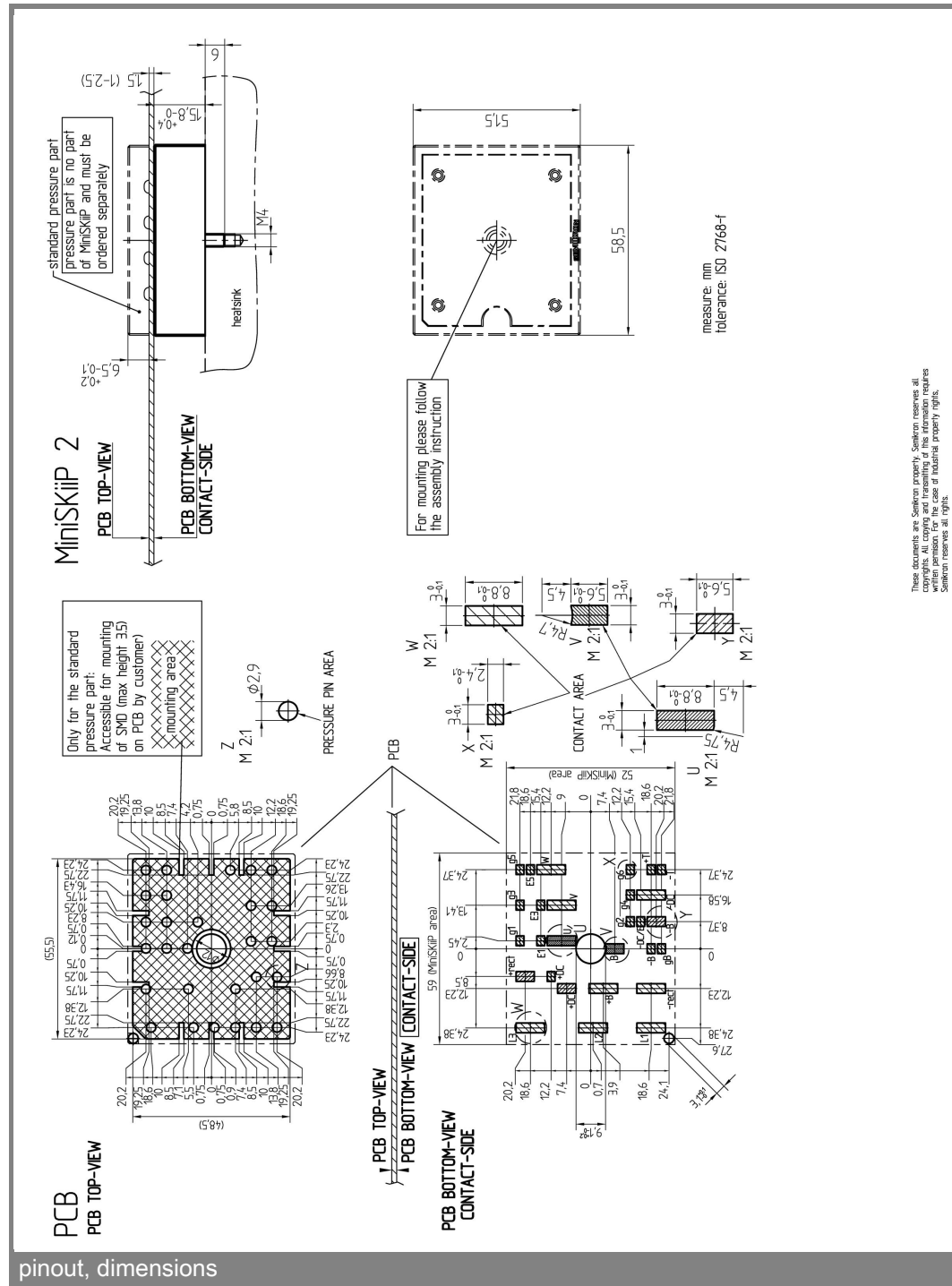
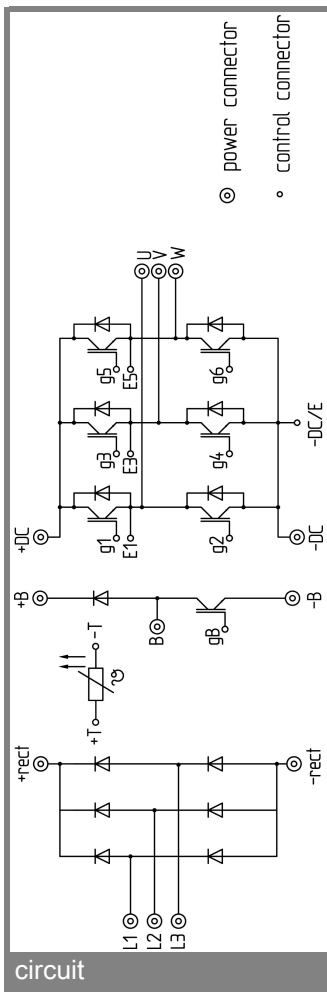
NAB

| Absolute Maximum Ratings  |                                    | T <sub>s</sub> = 25 °C, unless otherwise specified        |       |                  |
|---------------------------|------------------------------------|-----------------------------------------------------------|-------|------------------|
| Symbol                    | Conditions                         | Values                                                    | Units |                  |
| IGBT - Inverter, Chopper  |                                    |                                                           |       |                  |
| V <sub>CES</sub>          | T <sub>s</sub> = 25 (70) °C        | 1200                                                      | V     |                  |
| I <sub>C</sub>            |                                    | 52 (40)                                                   | A     |                  |
| I <sub>CRM</sub>          |                                    | 70                                                        | A     |                  |
| V <sub>GES</sub>          |                                    | ± 20                                                      | V     |                  |
| T <sub>j</sub>            |                                    | - 40 ... + 150                                            | °C    |                  |
| Diode - Inverter, Chopper |                                    |                                                           |       |                  |
| I <sub>F</sub>            | T <sub>s</sub> = 25 (70) °C        | 38 (29)                                                   | A     |                  |
| I <sub>FRM</sub>          |                                    | 70                                                        | A     |                  |
| T <sub>j</sub>            |                                    | - 40 ... + 150                                            | °C    |                  |
| Diode - Rectifier         |                                    |                                                           |       |                  |
| V <sub>RRM</sub>          | T <sub>s</sub> = 70 °C             | 1600                                                      | V     |                  |
| I <sub>F</sub>            |                                    | 46                                                        | A     |                  |
| I <sub>FSM</sub>          |                                    | t <sub>p</sub> = 10 ms, sin 180 °, T <sub>j</sub> = 25 °C | 370   | A                |
| i <sup>2</sup> t          |                                    | t <sub>p</sub> = 10 ms, sin 180 °, T <sub>j</sub> = 25 °C | 680   | A <sup>2</sup> s |
| T <sub>j</sub>            |                                    | - 40 ... + 150                                            | °C    |                  |
| Module                    |                                    |                                                           |       |                  |
| I <sub>tRMS</sub>         | per power terminal (20 A / spring) | 40                                                        | A     |                  |
| T <sub>stg</sub>          |                                    | - 40 ... + 125                                            | °C    |                  |
| V <sub>isol</sub>         | AC, 1 min.                         | 2500                                                      | V     |                  |

| Characteristics                  |                                                                               | $T_s = 25\text{ °C}$ , unless otherwise specified |            |           |       |
|----------------------------------|-------------------------------------------------------------------------------|---------------------------------------------------|------------|-----------|-------|
| Symbol                           | Conditions                                                                    | min.                                              | typ.       | max.      | Units |
| <b>IGBT - Inverter, Chopper</b>  |                                                                               |                                                   |            |           |       |
| $V_{CEsat}$                      | $I_{Cnom} = 35\text{ A}$ , $T_j = 25\text{ (125) °C}$                         |                                                   | 1,7 (2)    | 2,1 (2,4) | V     |
| $V_{GE(th)}$                     | $V_{GE} = V_{CE}$ , $I_C = 1,5\text{ mA}$                                     | 5                                                 | 5,8        | 6,5       | V     |
| $V_{CE(TO)}$                     | $T_j = 25\text{ (125) °C}$                                                    |                                                   | 1 (0,9)    | 1,2 (1,1) | V     |
| $r_T$                            | $T_j = 25\text{ (125) °C}$                                                    |                                                   | 20 (31)    | 26 (37)   | mΩ    |
| $C_{ies}$                        | $V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$           |                                                   | 2,4        |           | nF    |
| $C_{oes}$                        | $V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$           |                                                   | 0,5        |           | nF    |
| $C_{res}$                        | $V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$           |                                                   | 0,3        |           | nF    |
| $R_{th(j-s)}$                    | per IGBT                                                                      |                                                   | 0,75       |           | K/W   |
| $t_{d(on)}$                      | under following conditions                                                    |                                                   | 80         |           | ns    |
| $t_r$                            | $V_{CC} = 600\text{ V}$ , $V_{GE} = \pm 15\text{ V}$                          |                                                   | 30         |           | ns    |
| $t_{d(off)}$                     | $I_{Cnom} = 35\text{ A}$ , $T_j = 125\text{ °C}$                              |                                                   | 410        |           | ns    |
| $t_f$                            | $R_{Gon} = R_{Goff} = 15\text{ Ω}$                                            |                                                   | 120        |           | ns    |
| $E_{on}$                         | inductive load                                                                |                                                   | 4,6        |           | mJ    |
| $E_{off}$                        |                                                                               |                                                   | 4          |           | mJ    |
| <b>Diode - Inverter, Chopper</b> |                                                                               |                                                   |            |           |       |
| $V_F = V_{EC}$                   | $I_{Fnom} = 35\text{ A}$ , $T_j = 25\text{ (125) °C}$                         |                                                   | 1,8 (1,8)  | 2,1 (2,2) | V     |
| $V_{(TO)}$                       | $T_j = 25\text{ (125) °C}$                                                    |                                                   | 1 (0,8)    | 1,1 (0,9) | V     |
| $r_T$                            | $T_j = 25\text{ (125) °C}$                                                    |                                                   | 23 (31)    | 29 (37)   | mΩ    |
| $R_{th(j-s)}$                    | per diode                                                                     |                                                   | 1,5        |           | K/W   |
| $I_{RRM}$                        | under following conditions                                                    |                                                   | 43         |           | A     |
| $Q_{rr}$                         | $I_{Fnom} = 35\text{ A}$ , $V_R = 600\text{ V}$                               |                                                   | 7          |           | μC    |
| $E_{rr}$                         | $V_{GE} = 0\text{ V}$ , $T_j = 125\text{ °C}$<br>$di_F/dt = 1450\text{ A/μs}$ |                                                   | 3,3        |           | mJ    |
| <b>Diode - Rectifier</b>         |                                                                               |                                                   |            |           |       |
| $V_F$                            | $I_{Fnom} = 25\text{ A}$ , $T_j = 25\text{ °C}$                               |                                                   | 1,1        |           | V     |
| $V_{(TO)}$                       | $T_j = 150\text{ °C}$                                                         |                                                   | 0,8        |           | V     |
| $r_T$                            | $T_j = 150\text{ °C}$                                                         |                                                   | 13         |           | mΩ    |
| $R_{th(j-s)}$                    | per diode                                                                     |                                                   | 1,25       |           | K/W   |
| <b>Temperature Sensor</b>        |                                                                               |                                                   |            |           |       |
| $R_{ts}$                         | 3 %, $T_r = 25\text{ (100) °C}$                                               |                                                   | 1000(1670) |           | Ω     |
| <b>Mechanical Data</b>           |                                                                               |                                                   |            |           |       |
| w                                |                                                                               |                                                   | 65         |           | g     |
| $M_s$                            | Mounting torque                                                               | 2                                                 |            | 2,5       | Nm    |







This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.